Supporting Information for

Influence of Ethylene Thermal Decomposition on Carbon Nanotube Growth: Insights from a Two-Zone Reactor Study

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| T _p | Tg | Carbon yield | $I_{\rm G}/I_{\rm D}$ ratio | |
|----------------|------|----------------|-----------------------------|--|
| [°C] | [°C] | [%] | [-] | |
| 500 | 700 | 135.9 ± 11.9 | 1.52 ± 0.10 | |
| 600 | 700 | 131.1 ± 10.8 | 1.53 ± 0.10 | |
| 700 | 700 | 140.0 ± 17.8 | 1.46 ± 0.10 | |
| 800 | 700 | 201.8 ± 9.3 | 1.18 ± 0.14 | |
| 900 | 700 | 187.5 ± 17.3 | 2.13 ± 0.83 | |

Table S1. Carbon yield and I_G/I_D ratio as a function of T_p

Table S2. The composition and concentration of gases passing through the preheater at 25, 500, 600, 700, 800, and 900 °C using a micro-GC.

| Preheater temp. | C_2H_4 | H_2 | CH_4 | C_2H_6 | C_2H_2 | N_2 |
|-----------------|----------|---------|---------|----------|----------|---------|
| [°C] | [mole%] | [mole%] | [mole%] | [mole%] | [mole%] | [mole%] |
| 25 | 20.2 | 11.1 | | | | 68.8 |
| 500 | 20.2 | 11.0 | | | | 68.8 |
| 600 | 20.0 | 10.9 | | 0.1 | | 69.0 |
| 700 | 17.5 | 9.9 | | 1.6 | | 70.9 |
| 800 | 10.3 | 12.3 | 4.9 | 1.1 | 0.3 | 71.1 |
| 900 | 1.7 | 21.4 | 8.4 | 0.1 | 0.3 | 68.1 |



Fig. S1. Decoupled growth recipes at T_g of 700 °C, with T_p of (a) 500, (b) 600, (c) 700, and (d) 800 °C.



Fig. S2. Raman spectra of CNT synthesized at T_p of (a) 500, (b) 600, (c) 700, (d) 800, and (e) 900 °C.



Fig. S3. TGA curves for synthesized CNTs at T_p of (a) 700, (b) 800, and (c) 900 °C.



Fig. S4. Scheme of gas analysis using micro-GC.